

M5L8216P/M5L8226P

T-52-09

MITSUBISHI(MICMPTR/MIPRC)

4-BIT PARALLEL BIDIRECTIONAL BUS DRIVERS**DESCRIPTION**

The M5L8216P and M5L8226P are 4-bit bidirectional bus drivers and suitable for the 8-bit parallel CPU M5L8085AP.

FEATURES

- Parallel 8-bit data bus buffer driver
- Low input current DIEN, CS:
DI, DB: $I_{IL} = -500\mu A$ (max.)
DO: $I_{OH} = -250\mu A$ (max.)
- High output current M5L8216P
DB: $I_{OL} = 55mA$ (max.)
 $I_{OH} = -10mA$ (max.)
DO: $I_{OH} = -1mA$ (max.)
- M5L8226P
DB: $I_{OL} = 50mA$ (max.)
 $I_{OH} = -10mA$ (max.)
DO: $I_{OH} = -1mA$ (max.)
- Outputs can be connected with the CPU M5L8085AP: $V_{OH} = 3.65V$ (min.)
- Three-state output

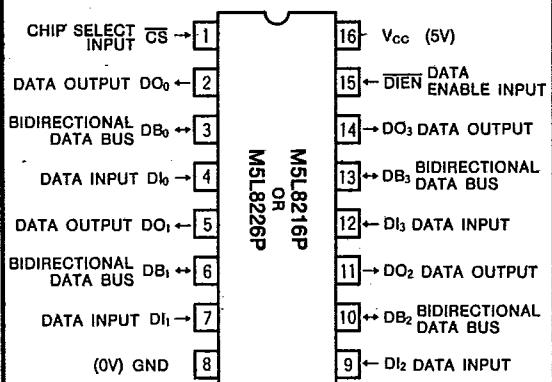
APPLICATION

Bidirectional bus driver/receiver for various types of micro-computer systems.

FUNCTION

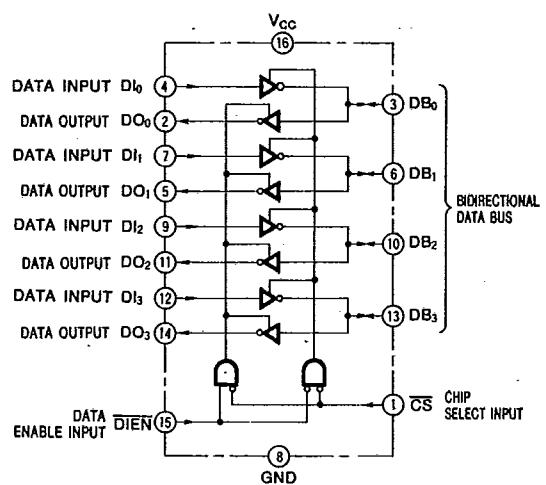
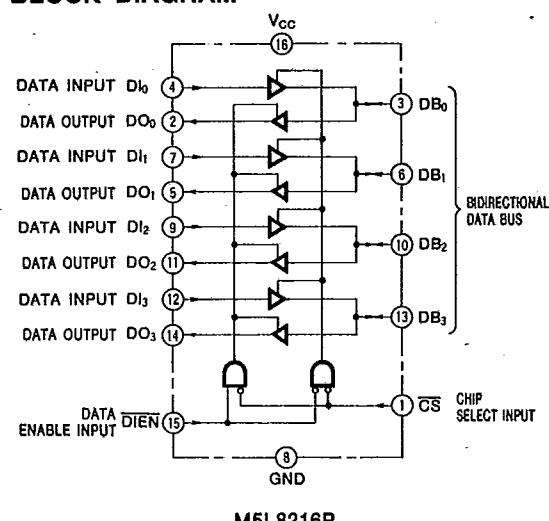
The M5L8216P is a non-inverting and the M5L8226P is an inverting 4-bit bidirectional bus driver.

When the terminal CS is high-level, all outputs are in high-impedance state, and when low-level, the direction of the bidirectional bus can be controlled by the terminal DIEN.

PIN CONFIGURATION (TOP VIEW)

Outline 16P4

The terminal DIEN controls the data flow. The data flow control is performed by placing one of a pair of buffers in high-impedance state and allowing the other to transfer the data.

BLOCK DIAGRAM

29E D ■ 6249828 0014872 6 ■

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4-BIT PARALLEL BIDIRECTIONAL BUS DRIVERS**ABSOLUTE MAXIMUM RATINGS** ($T_a=0\sim75^\circ C$, unless otherwise noted)

| Symbol | Parameter | Conditions | Ratings | Unit |
|-----------|--------------------------------------|---------------------|----------|------|
| V_{CC} | Supply voltage | With respect to GND | 7 | V |
| V_I | Input voltage, CS, DIEN, DI inputs | | 5.5 | V |
| V_I | Input voltage, DB Input | | V_{CC} | V |
| V_O | High-level output voltage | | V_{CC} | V |
| P_d | Power dissipation | $T_a=25^\circ C$ | 700 | mW |
| T_{opr} | Operating free-air temperature range | | 0~75 | °C |
| T_{stg} | Storage temperature range | | -65~+150 | °C |

RECOMMENDED OPERATING CONDITIONS ($T_a=0\sim75^\circ C$, unless otherwise noted)

| Symbol | Parameter | Limits | | | Unit |
|----------|--------------------------------------|--------|-----|------|------|
| | | Min | Nom | Max | |
| V_{CC} | Supply voltage | 4.75 | 5 | 5.25 | V |
| I_{OH} | High-level output current, DO output | | | -1 | mA |
| I_{OH} | High-level output current, DB output | | | -10 | mA |
| I_{OL} | Low-level output current, DO output | | | 15 | mA |
| I_{OL} | Low-level output current, DB output | | | 25 | mA |

ELECTRICAL CHARACTERISTICS ($T_a=0\sim75^\circ C$, unless otherwise noted)

| Symbol | Parameter | Conditions | Limits | | | Unit |
|-----------|---|---|----------------|------|------|---------|
| | | | Min | Typ | Max | |
| V_{IH} | High-level input voltage | | 2 | | | V |
| V_{IL} | Low-level input voltage | | | | 0.95 | V |
| V_{IC} | Input clamp voltage | $V_{CC}=4.75V, I_{IO}=-5mA$ | | | -1 | V |
| V_{OH} | High-level output voltage, DO output | $V_{CC}=4.75V$ $V_{IH}=2V$ $V_{IL}=0.95V$ | $I_{OH}=-1mA$ | 3.65 | | V |
| V_{OH} | High-level output voltage, DB output | | $I_{OH}=-10mA$ | 2.4 | | V |
| V_{OL1} | Low-level output voltage, DO output | | $I_{OL}=15mA$ | | 0.45 | V |
| V_{OL1} | Low-level output voltage, DB output | | $I_{OL}=25mA$ | | 0.45 | V |
| V_{OL2} | Low-level output voltage, DB output | | $I_{OL}=55mA$ | | 0.6 | V |
| | M5L8216P | | $I_{OL}=50mA$ | | 0.6 | |
| I_{OZH} | Off-state output current, DO output | $V_{CC}=5.25V$ | $V_O=5.25V$ | | 20 | μA |
| I_{OZH} | Off-state output current, DB output | | | | 100 | μA |
| I_{OZL} | Off-state output current, DO output | | $V_O=0.45V$ | | -20 | μA |
| I_{OZL} | Off-state output current, DB output | | | | -100 | μA |
| I_{IH} | High-level input current, DIEN, CS inputs | $V_{CC}=5.25V, V_{IH}=4.5V$ | | | 20 | μA |
| I_{IH} | High-level input current, DI, DB inputs | | | | 10 | μA |
| I_{IL} | Low-level input current, DIEN CS inputs | | | | -500 | μA |
| I_{IL} | Low-level input current, DI, DB input | $V_{CC}=5.25V, V_{IH}=4.5V$ | | | -250 | μA |
| I_{os} | Short-circuit output DO output (Note 2) | $V_{CC}=5.25V, V_O=0V$ | | -15 | | mA |
| I_{os} | Short-circuit output, DB output (Note 2) | | | -30 | | mA |
| I_{cc} | Supply current | $V_{CC}=5.25V$ | | | 100 | mA |
| | M5L8216P | | | | 100 | |
| | M5L8226P | | | | 120 | |
| | M5L8216P | | | | 100 | |
| | M5L8226P | | | | 100 | |

Note 1 : Current flowing into an IC is positive, out is negative.

2 : All measurements should be done quickly, and not more than one output should be shorted at a time.

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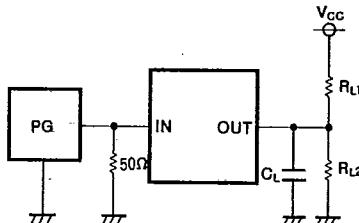
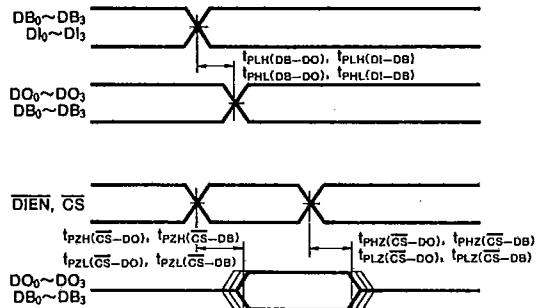
4-BIT PARALLEL BIDIRECTIONAL BUS DRIVERS

SWITCHING CHARACTERISTICS ($V_{CC}=5V \pm 5\%$, $T_a=25^\circ C$, unless otherwise noted)

| Symbol | Parameter | Test conditions (Note 3) | Limits | | | Unit |
|------------------------|--|--|--------|-----|-----|------|
| | | | Min | Typ | Max | |
| $t_{PHL(DB-DO)}$ | High-to-low and low-to-high output propagation time, from input DB to output DO | $C_L=30pF, R_{L1}=300\Omega, R_{L2}=600\Omega$ | | | 25 | ns |
| $t_{PLH(DB-DO)}$ | High-to-low and low-to-high output propagation time, from input DI to output DB | M5L8216P $C_L=300pF, R_{L1}=90\Omega, R_{L2}=180\Omega$ M5L8226P | | | 30 | ns |
| $t_{PHL(\bar{CS}-DO)}$ | High-to-Z and low-to-Z output propagation time, from inputs DIEN, CS, to output DO | $C_L=5pF, R_{L1}=10k\Omega, R_{L2}=1k\Omega$ $C_L=5pF, R_{L1}=300\Omega, R_{L2}=600\Omega$ | | | 25 | ns |
| $t_{PLZ(\bar{CS}-DO)}$ | Output enable time, from Inputs DIEN, CS to output DO | M5L8216P $C_L=30pF, R_{L1}=10k\Omega, R_{L2}=1k\Omega$ M5L8226P $C_L=300pF, R_{L1}=90\Omega, R_{L2}=180\Omega$ | | | 35 | ns |
| $t_{PZH(\bar{CS}-DO)}$ | Output disable time, from inputs DIEN, CS, to output DB | M5L8216P $C_L=5pF, R_{L1}=10k\Omega, R_{L2}=1k\Omega$ M5L8226P $C_L=5pF, R_{L1}=90\Omega, R_{L2}=180\Omega$ | | | 65 | ns |
| $t_{PZL(\bar{CS}-DO)}$ | Output enable time, from inputs DIEN, CS, to output DB | M5L8216P $C_L=300pF, R_{L1}=10k\Omega, R_{L2}=1k\Omega$ M5L8226P $C_L=300pF, R_{L1}=90\Omega, R_{L2}=180\Omega$ | | | 54 | ns |
| $t_{PHZ(\bar{CS}-DB)}$ | Output disable time, from inputs DIEN, CS, to output DB | M5L8216P $C_L=5pF, R_{L1}=10k\Omega, R_{L2}=1k\Omega$ M5L8226P $C_L=5pF, R_{L1}=90\Omega, R_{L2}=180\Omega$ | | | 65 | ns |
| $t_{PLZ(\bar{CS}-DB)}$ | Output enable time, from inputs DIEN, CS, to output DB | M5L8216P $C_L=300pF, R_{L1}=10k\Omega, R_{L2}=1k\Omega$ M5L8226P $C_L=300pF, R_{L1}=90\Omega, R_{L2}=180\Omega$ | | | 54 | ns |

TIMING DIAGRAM (Reference level=1.5V)

Note 3 : Test circuit



APPLICATION EXAMPLES

Fig. 1 shows a pair of M5L8216Ps or M5L8226Ps which are directly connected with the 8080A CPU data bus, and their control signal. Fig. 2 shows an example circuit in which the M5L8216P or M5L8226P is used as an interface for memory and I/O to a bidirectional bus.

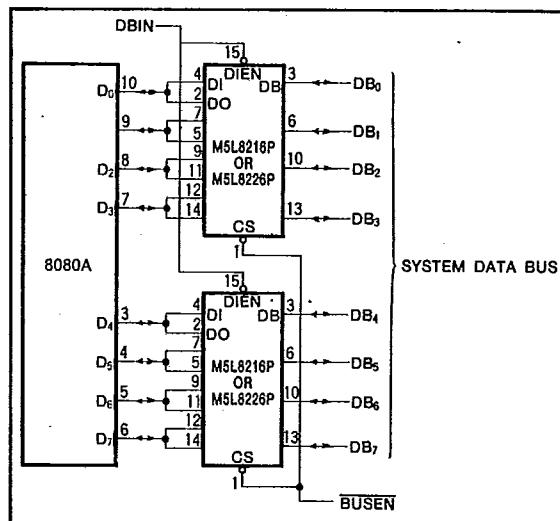


Fig. 1 Data bus buffer

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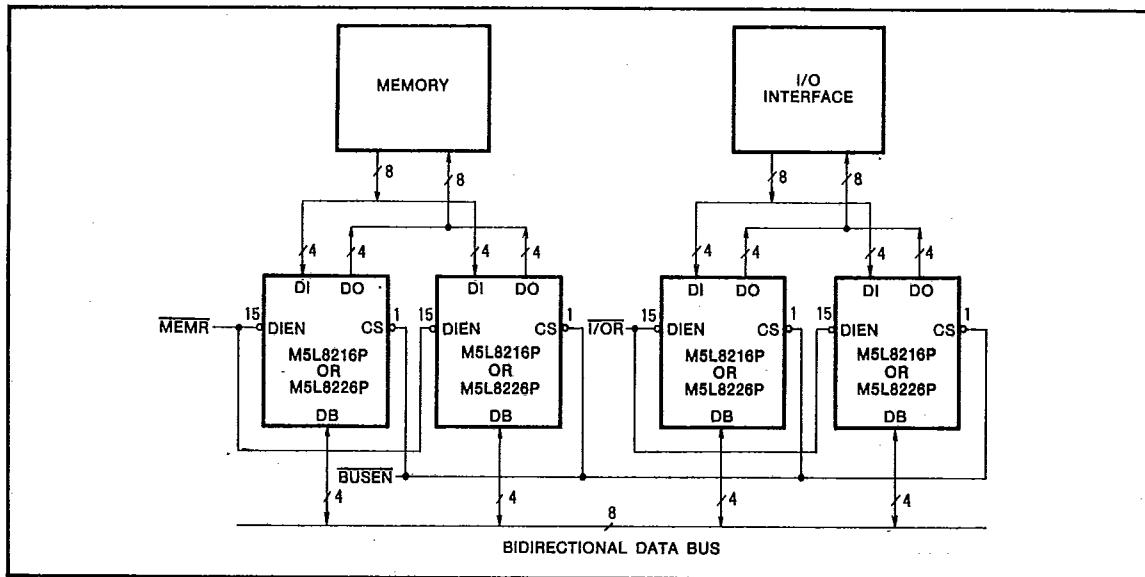
4-BIT PARALLEL BIDIRECTIONAL BUS DRIVERS

Fig. 2 Memory and I/O Interface to bidirectional data bus

PRECAUTIONS FOR USE

When the M5L8216P data input or two-way data bus is set to high to disable-output from the two-way bus or data output, care is required as a low glitch of approximate width 10ns will be generated.